

ChipSESD

Silicon ESD Protector
Overvoltage Protection Device

PRODUCT: SESD0201P1BN-0400-090

DOCUMENT: SCD27763 REV LETTER: B

REV DATE: JULY 26, 2016 PAGE NO.: Page 1 of 5

Specification Status: Released

BENEFITS

- Silicon ESD device in an EIA-0201 size rectangular passive component SMT package
- Standard PCB assembly and rework processes
- Bi-directional operation allows placement on PCB without orientation constraint
- Appropriate for ESD protection in space-constrained portable electronics and mobile handsets
- Suitable for +5V operating voltage applications
- Helps protect electronic circuits against damage from Electrostatic Discharge (ESD) events
- Assist equipment to pass IEC61000-4-2, level 4 testing
- RoHS compliant and Halogen Free

FEATURES

- Input capacitance 4pF (typ)
- Low leakage current 1.0µA (max)
- Low working reverse voltage 6.0V (max)
- ESD maximum rating per IEC61000-4-2 standard
 - o ± 10kV contact discharge (1)
 - o ± 16kV air discharge
- Capable of withstanding numerous ESD strikes
- Small package size: 0.60mm x 0.30mm (typ)
- Low package height: 0.30mm (typ)

APPLICATIONS

- Cellular phones and portable electronics
- Digital cameras and camcorders
- USB 2.0 and computer I/O ports
- Keypads, pushbuttons, low voltage DC lines, speakers, headphones, microphones
- Applications requiring high ESD performance

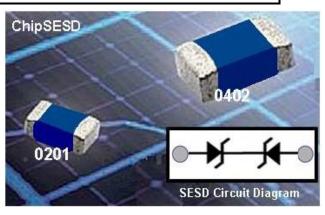
RoHS Compliant ELV Compliant Halogen Free *



Directive 2002/95/EC Compliant

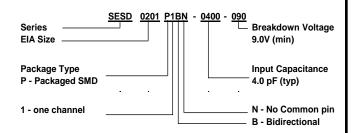


* Halogen Free refers to: Br≤900ppm, Cl≤900ppm, Br+Cl≤1500ppm Terminal finish: 100% Matte Tin (Sn)



PART NUMBERING

MATERIALS INFORMATION





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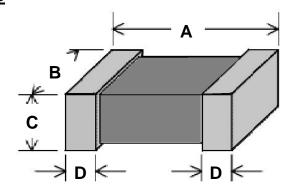
REV LETTER: B

REV DATE: JULY 26, 2016 PAGE NO.: Page 2 of 5

Device Characteristics @ T = 25°C	Min	Тур	Max	Unit
Input Capacitance @ V _r = 0V, f = 1MHz		4.0	5.0	pF
Working Reverse Voltage (peak) - V _{RWM}			6.0	V
Breakdown Voltage – V _{br} @ I _t = 1mA ⁽²⁾	9.0	11.0		V
Leakage current @ V _{RWM} = 6.0V			1.0	μA
Clamping Voltage @ Ipp=2A, tp=(8/20µs)		±10.0	±12.0	V
ESD contact discharge per IEC61000-4-2 standard (1)			±10	kV
ESD air discharge per IEC61000-4-2 standard			±16	kV
Operating (T _{junction}) and Storage Temperature Range -40 to +125			•	°C

^{(1) 10}kV @ ± 50 pulses under IEC61000-4-2; 8kV @ 1,000 pulses under IEC61000-4-2

DEVICE DIMENSIONS

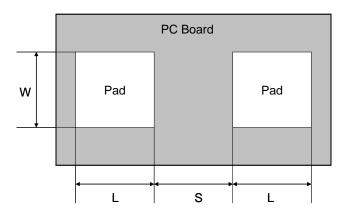


Drawing Not To Scale

Typical	А	В	С	D
mm	0.60 ± 0.05	0.30 ± 0.05	0.30 ± 0.05	0.21 ± 0.07
mils*	23.62 ± 2.0	11.81 ± 2.0	11.81 ± 2.0	8.27 ± 2.8

^{*} Round off approximation

RECOMMENDED LANDING PATTERN:



⁽²⁾ V_{br} is measured at test current I_t



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	L	S	W
mm	0.28 ± 0.01	0.19 ± 0.01	0.30 ± 0.01
mils*	11.0 ± 0.4	7.5 ± 0.4	11.8 ± 0.4

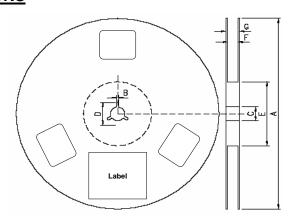
^{*} Round off approximation

- ullet Recommended solder thickness: 150 to 200 um
- Recommended rework procedure:
 - o Soldering iron tip temperature should be less than 350°C
 - Apply iron tip to solder for less than 5 seconds
 - Do not apply solder iron tip to the body of this product directly

PACKAGING

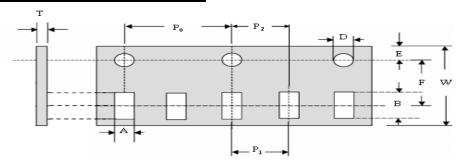
Packaging	Tape & Reel	Standard Box	
SESD0201P1BN-0400-090	15,000	75,000	

REEL DIMENSIONS



Dimension	Α	В	С	D	E	F	G
(mm)	178.0 ± 2.0	2.0 ± 0.5	13.0 ± 0.5	21.0 ± 0.8	62.0 ± 1.5	9.0 ± 0.5	13.0 ± 1.0

CARRIER TAPE DIMENSIONS





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DOCUMENT: SCD27763

REV LETTER: B

REV DATE: JULY 26, 2016 PAGE NO.: Page 4 of 5

Dimension	Α	В	D	E	F	W
(mm)	0.39 ± 0.03	0.69 ± 0.03	1.55 ± 0.05	1.75 ± 0.05	3.5 ± 0.05	8.0 ± 0.1

Dimension	P_0	P ₁	P ₂	Т	
(mm)	4.0 ± 0.1	2.0 ± 0.05	2.0 ± 0.05	0.42 ± 0.03	

FIGURE 1: TYPICAL IV CURVE

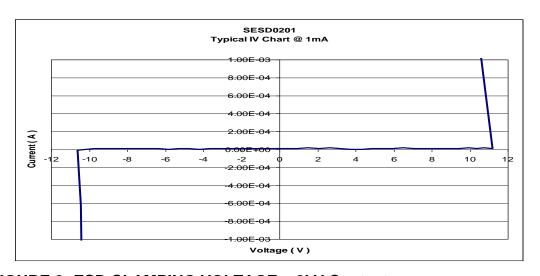
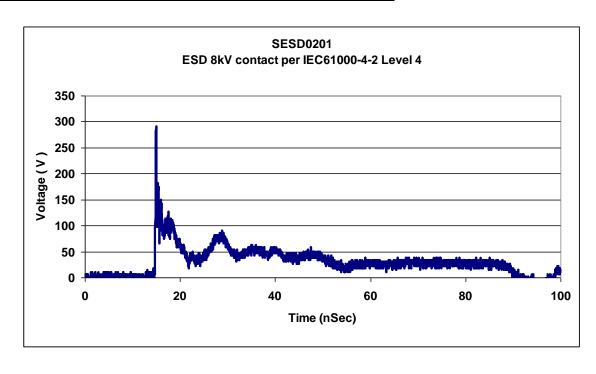


FIGURE 2: ESD CLAMPING VOLTAGE - 8kV Contact





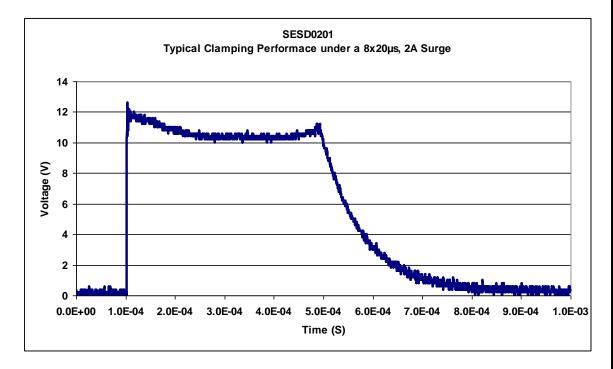
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FIGURE 3: ESD CLAMPING VOLTAGE - 8x20µs, 2A Surge



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ESD119B1W01005E6327XTSA1 ESD5V0J4-TP ESD5V0L1B02VH6327XTSA1 ESD7451N2T5G 19180-510 CPDT-5V0USP-HF
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